

Single-Channel Power Distribution Switch

Description

The FP6861G is a low $R_{DS(ON)}$, low power loss, single N-Channel MOSFET high-side power switch, optimized for self-powered and bus-powered Universal Serial Bus (USB) applications.

The FP6861G is equipped with a charge pump circuitry to drive the internal MOSFET switch. The switch's low $R_{DS(ON)}$ meets USB voltage drop requirement, and a flag output is available to indicate fault conditions to the local USB controller.

Additional features include soft-start to limit inrush current during plug-in, thermal shutdown to prevent catastrophic switch failure from high-current loads, and Under-Voltage Lockout (UVLO) to ensure that the device remains off unless there is a valid input voltage present. Besides, fault current is limited to specific current for FP6861G in single port in accordance with the USB power requirements. FP6861G will prevent reverse current when it is disabled and VOUT is higher than VIN.

The FP6861G is available in FC-SOT-23-5, SOT-23-5 and MSOP-8 packages with smallest components.

Features

- Compliant to USB Specifications
- Built-In Low R_{DS(ON)} 45mΩ N-Channel MOSFET (for FP6861G-A/B/C)
- Built-In Low R_{DS(ON)} 70mΩ N-Channel MOSFET
- (for FP6861G-D)
- Two Enable Polarity: Active High or Active Low
- Output can be Forced Higher than Input (Off-State)
- Low Supply Current:
 35µA Typical at Switch On State
 0.1µA Typical at Switch Off State
- 2.5V to 5.5V Input Voltage Range
- Open-Drain Fault Flag Output
- Hot Plug-In Application (Soft-Start)
- 2.45V Typical Under-Voltage Lockout (UVLO)
- Current Limit Protection
- Thermal Shutdown Protection
- Reverse Current Flow Blocking (No Body Diode)
- Logic Level Enable Pin
- FC-SOT-23-5, SOT-23-5 and MSOP-8 Packages
- RoHS Compliant
- UL NO.E322418 (Approved model: FP6861 Series)
- CB Test Certified, Ref. Certif. No. JPTUV-101402

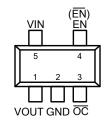
Applications

- USB Bus/Self Powered Hub
- USB Peripheral
- ACPI Power Distribution
- Notebook, Motherboard PC
- Battery-Charger Circuit



Pin Assignments

S5 Package (SOT-23-5)



MS Package (MSOP-8)

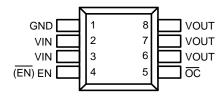
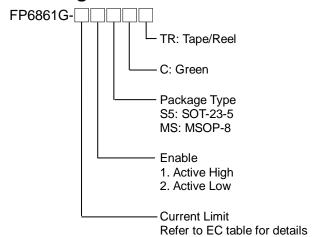


Figure 1. Pin Assignment of FP6861G

Ordering Information



SOT-23-5 Marking

Product Code	
FX5	(FC)
FX6	(FC)
FX7	(FC)
FX8	(FC)
GD3	(FC)
GE3	
	FX5 FX6 FX7 FX8 GD3



Typical Application Circuit

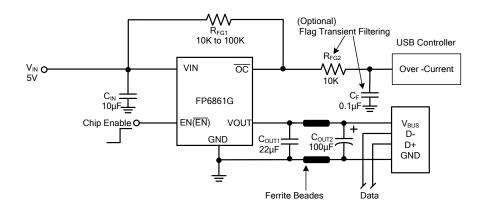


Figure 2. Typical Application Circuit

Functional Pin Description

Pin Name	SOT-23-5 Pin No.	MSOP-8 Pin No.	Pin Function
VOUT	1	6, 7, 8	Switch output.
GND	2	1	Ground.
oc	3	5	Open-drain fault flag output.
EN	4	4	Chip enable. Pull the pin high to enable IC; pull the pin low to shutdown IC. Do not let the pin floating.
EN	4	4	Chip shutdown. Pull the pin high to shutdown IC; pull the pin low to enable IC. Do not let the pin floating.
VIN	5	2,3	Input power supply.

Block Diagram

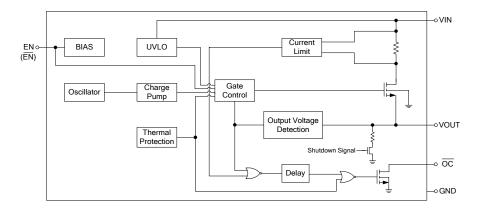


Figure 3. Block Diagram





Absolute Maximum Ratings (Note 1)

• VIN, VOUT	0.3V to +6.5V
• EN (EN)	0.3V to +6.5V
• OC	0.3V to +6.5V
• Power Dissipation @ T _A =25°C, (P _D)	
SOT-23-5 (FC)	- 1.18W
SOT-23-5	- 0.4 W
MSOP-8	0.63W
 Package Thermal Resistance, (θ_{JA}) (Note 2) 	
SOT-23-5 (FC)	- 85°C/W
SOT-23-5	- 250°C/W
MSOP-8	160°C/W
$ullet$ Package Thermal Resistance, (θ_{JC})	
SOT-23-5 (FC)	- 20°C/W
SOT-23-5	- 130°C/W
MSOP-8	75°C/W
Junction Temperature	+150°C
• Lead Temperature (Soldering,10 sec.)	+260°C
Storage Temperature Range	65°C to +150°C
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Note 1: Stresses beyond this listed under "Absolute Maximum Ratings" may cause permanent damage to the device. Note 2: θ_{JA} is measured at 25°C ambient with the component mounted on a high effective thermal conductivity 4-layer board of JEDEC-51-7. The thermal resistance greatly varies with layout, copper thickness, number of layers and PCB size.

Recommended Operating Conditions

• Supply Voltage (V _{IN})	+2.5V to +5.5V
Junction Temperature Range (T _{OPR})	-40°C to +125°C
Operation Temperature Range (T _{OPR})	-40°C to +85°C



Electrical Characteristics

(V_{IN}=5V, T_A=25°C, unless otherwise specified.)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit	
Cuitab On Desistance	D	I _{OUT} =500mA, FP6861G-A/B/C		45	65	mΩ	
Switch On Resistance	R _{DS(ON)}	I _{OUT} =500mA, FP6861G-D		70		mΩ	
Supply Current (Note 3)	I _{SW_ON}	Switch on, V _{OUT} = Open		35			
Supply Current ()	I _{SW_OFF}	Switch off, V _{OUT} = Open		0.1	1	μA	
ENITE	V _{IL}	Switch off			0.8		
EN Threshold	V _{IH}	Switch on	1.5			V	
EN Input Current	I _{EN}	V _{EN} =Enable		0.01	0.1	μA	
		R _{LOAD} =1Ω, FP6861G-A	3.2	3.76	4.43	Α	
Occurred Line in		R _{LOAD} =1Ω, FP6861G-B	2.56	3	3.54	Α	
Current Limit	I _{LIM}	R _{LOAD} =1Ω, FP6861G-C	2.2	2.6	2.9	Α	
		R _{LOAD} =1Ω, FP6861G-D		2.6	2.9	Α	
	I _{SC_FB}	V _{OUT} =0V, FP6861G-A		2.1	2.8	Α	
Short Circuit Fold-Back		V _{OUT} =0V, FP6861G-B		1.68	2.24	Α	
Current		V _{OUT} =0V, FP6861G-C		1.45	2.15	Α	
		V _{OUT} =0V, FP6861G-D		1.45	2.15	Α	
Output Leakage Current	I _{LEAKAGE}	V_{EN} =Disable, R_{LOAD} = 0Ω		0.5	1	μA	
OC Output Resistance	R _{oc}	I _{SINK} =1mA		100		Ω	
OC Off Current	I _{oc}	V _{OC} = 5V		0.01		μA	
OC Delay Time t _D		From Fault Condition to OC Assertion		10		ms	
Under-Voltage Lockout	V _{UVLO}	V _{IN} Increasing			2.45	V	
Under-Voltage Hysteresis	ΔV_{UVLO}	V _{IN} Decreasing		0.1		V	
Shutdown Pull Low Resistance	R _{PD}			63		Ω	
Thermal Shutdown Threshold (Note 4)	T _{SD}			150		°C	
Threshold (Note 4)	ΔT_{SD}	Hysteresis		20		°C	

Note 3: Supply Current Test Condition of the I_{SW_ON} is $V_{IN}=V_{EN}$. Note 4: Guarantee by design.



Typical Performance Curves

 $V_{\text{IN}} = V_{\text{OUT}} = 5V$, $C_{\text{IN}} = 100 \mu\text{F}$, $C_{\text{OUT}} = 120 \mu\text{F}$, TA=+25°C, unless otherwise noted. This is measured by using FP6861G-A1S5CTR.

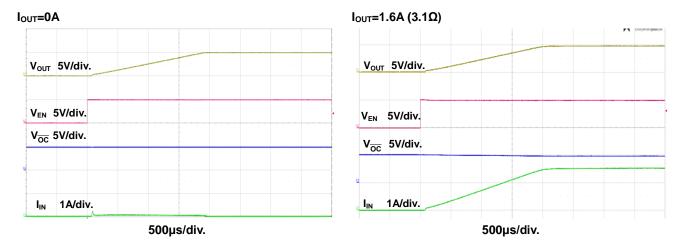


Figure 4. EN Start-Up

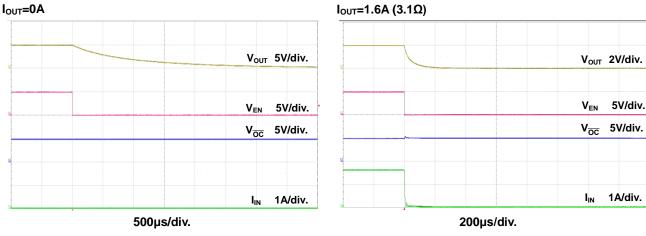


Figure 6. EN Power Off Test

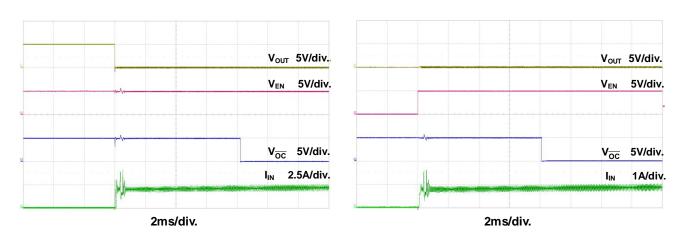


Figure 8. Inrush Short Circuit Response

Figure 9. Short Circuit Response at Start Up

FP6861G-0.9-SEP-2020 6

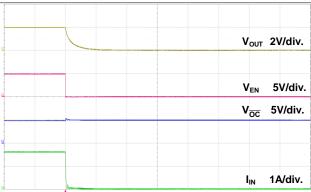


Figure 7. EN Power Off Test

Figure 5. EN Start-Up



Typical Performance Curves (Continued)

 $V_{\text{IN}} = V_{\text{OUT}} = 5\text{V}, \ C_{\text{IN}} = 100 \mu\text{F}, \ C_{\text{OUT}} = 22 \mu\text{F}, \ TA = +25 ^{\circ}\text{C}, \ unless \ otherwise noted. This is measured by using FP6861G-A1S5CTR.}$

I_{OUT}=0A~3A



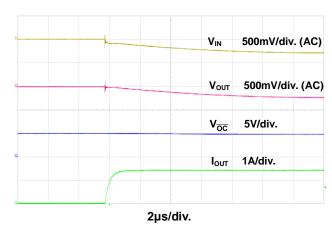
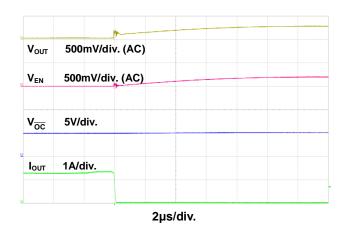


Figure 10. Load transient

Figure 11. Output Load Insert Hot Plug-In with 3.1Ω (1.6A)



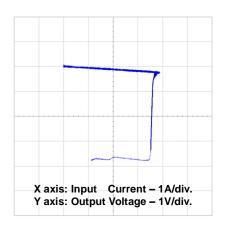


Figure 12. Output Load Insert Hot Plug-Off with 3.1Ω (1.6A)

Figure 13. Over Current Protection Characteristics



Typical Performance Curves (Continued)

V_{IN}= V_{OUT}=5V, C_{IN}=100μF, C_{OUT}=22μF, TA=+25°C, unless otherwise noted. This is measured by using FP6861G-A1S5CTR.

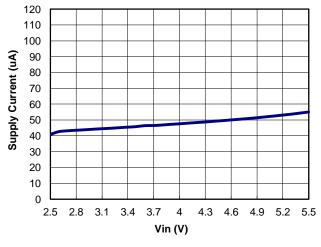


Figure 14. Supply Current vs. Input Voltage

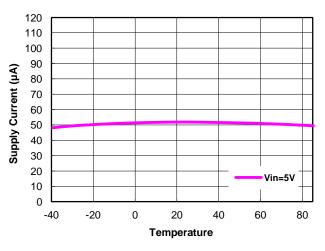


Figure 16. Supply Current vs. Temperature

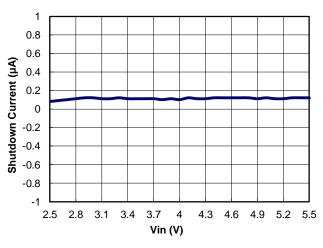


Figure 15. Shutdown Current vs. Input Voltage

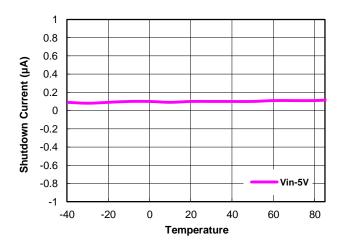


Figure 17. Shutdown Current vs. Temperature



Application Information

The FP6861G is a single N-Channel MOSFET high-side power switch, optimized for self-powered and bus-powered Universal Serial Bus (USB) applications. The FP6861G operates from 2.5V to 5.5V input voltage range and provides low supply current. The switch's low $R_{\rm DS(ON)},\ 45 {\rm m}\Omega$ or $70 {\rm m}\Omega,$ meets USB voltage drop requirements. It has one switch with enable control input. The switch has an error flag output to notify the USB controller when the current-limit, short-circuit or thermal-shutdown occurs.

Under-Voltage Lockout

Under-Voltage Lockout (UVLO) prevents the MOSFET switch from turning on until input voltage exceeds approximately 2.45V. If input voltage drops below approximately 2.35V, UVLO will turn off the MOSFET switch.

Thermal Shutdown

Thermal shutdown is employed to protect the device from damage if the die temperature exceeds safe margins mainly due to short-circuit or current-limit. Thermal shutdown will shut the switch off and cause the \overline{OC} output to go low.

Reverse Current Blocking

The USB specification does not allow an output device to source current back into the USB port. However, the FP6861G is designed to safely power noncompliant devices. When the device is disabled, the output will be switched to a high-impedance state, blocking reverse current flow from the output back to the input. The switch is bidirectional when it is enabled.

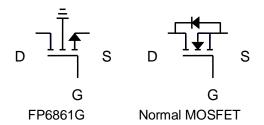
Error Flag

The FP6861G provides an open drain error flag output for the switch. For most applications, connect \overline{OC} to VIN through a pull-up resistor. \overline{OC} will go low when any following condition occurs:

- a. The thermal shutdown occurs.
- b. The switch is in current limit or short circuit conditions.

Input and Output

VIN is the power source connection to the internal circuitry and the drain of the MOSFET. VOUT is the source of the MOSFET. In typical application, current flows through the switch from VIN to VOUT toward the load. If VOUT is greater than VIN, current will flow from VOUT to VIN since the MOSFET is bidirectional. There is no parasitic body diode between drain and source of the MOSFET, and the FP6861G will prevent reverse current flow if VOUT externally forces a higher voltage than VIN when the output is disabled.



Soft Start for Hot Plug-In Application

In order to eliminate the upstream voltage drop caused by the large inrush current during hot-plug events, the "soft-start" feature effectively isolates the power source from extremely large capacitive loads, satisfying the USB voltage drop requirements.

Current Limit and Short-Circuit Protection

The current limit circuitry prevents damage to the MOSFET switch and the hub downstream port but can deliver load current up to the current limit threshold through the switch of FP6861G. When a heavy load or short circuit is applied to an enabled switch, a large transient current may flow until the current limit circuitry responds. Once exceeds the current limit threshold, the device will enter constant current mode until the thermal shutdown occurs or the fault is removed.

Fast Shutdown Load Discharge

The FP6861G provides a pull down resistance when the device is off. The resistance could discharge the load capacitor fast (refer to the block diagram).



Application Information (Continued)

Supply Filter/Bypass Capacitor

The input capacitor must be at least $1\mu F$ low-ESR ceramic capacitor connected from VIN to GND, but can be increased without limit. Output short may cause sufficient ringing on the input (from source lead inductance) to destroy the internal control circuitry. The input transient must not exceed 6.5V of the absolute maximum supply voltage even for a short duration.

Output Filter Capacitor

Output is recommended to use a $22\mu F$ ceramic capacitor in parallel with a $100\mu F$ electrolytic capacitor. Standard bypass methods should be used to minimize inductance and resistance between the bypass capacitor and the downstream connector which reduce EMI and decouple voltage drop caused when downstream cables are hot-insertion transients. Ferrite beads in series with V_{BUS} , the ground line and the $0.1\mu F$ bypass capacitors at the power connector pins are recommended for EMI and ESD protection. The bypass capacitor should have a low dissipation factor to allow decoupling at higher frequencies.

Power Dissipation

The device's junction temperature depends on several factors, such as the load, PCB layout, ambient temperature and package type. However, the maximum output current must be decreased at higher ambient temperature to ensure the junction temperature does not exceed 125°C. With all possible conditions, the junction temperature must be within the range specified under operating conditions. Power dissipation can be calculated based on the output current and the $R_{\text{DS}(\text{ON})}$ of switch as below:

$$P_D = R_{DS(ON)} \times (I_{OUT})^2$$

Although the devices are rated by current limit, but the application may limit the amount of output current based on the total power dissipation and the ambient temperature. The final operating junction temperature for any set of conditions can be estimated by the following thermal equation:

$$P_{D(MAX)} = \frac{T_{J(MAX)} - T_A}{\theta_{JA}}$$

Where $T_{J(MAX)}$ is the maximum junction temperature 125°C, T_A is the ambient temperature and the θ_{JA} is the junction to ambient thermal resistance.

The junction to ambient thermal resistance θ_{JA} is related to layout. For FC-SOT-23-5 package, the thermal resistance θ_{JA} is 85°C/W on the standard JEDEC 51-7 four-layer thermal test board.

PCB Layout

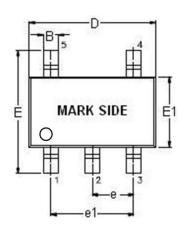
In order to meet the voltage drop and EMI requirements, careful PCB layout is necessary. The following guidelines must be considered:

- Keep all V_{BUS} traces as short as possible, and use at least 50-mil and 2 ounce copper for all V_{BUS} traces.
- Locate the FP6861G as close to the output port as possible to limit switching noise.
- Locate the ceramic bypass capacitors as close to the VIN pins of the FP6861G as possible.
- Avoid vias as much as possible. If vias are necessary, make them as large as feasible.
- Place a ground plane under all circuitry to lower both resistance and inductance, and improve DC and transient performance (use a separate ground and power plans if possible).
- Place cuts in the ground plane between ports to help reducing the coupling of transients between ports.
- Locate the output capacitor and ferrite beads as close to the USB connectors as possible to lower impedance (mainly inductance) between the port and the capacitor, and improve transient load performance.

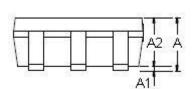


Outline Information

SOT-23-5 Package (Unit: mm)





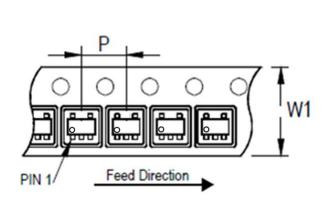


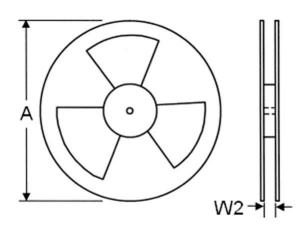
SYMBOLS	DIMENSION IN MILLIMETER				
UNIT	MIN	MAX			
Α	0.90	1.45			
A1	0.00	0.15			
A2	0.90	1.30			
В	0.25	0.50			
D	2.80	3.00			
E	2.60	3.00			
E1	1.50	1.70			
е	0.90	1.00			
e1	1.80	2.00			
L	0.30	0.60			

Note 5: Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.3mm.

Note 6: Reference JEDEC MO-178.

Carrier Dimensions



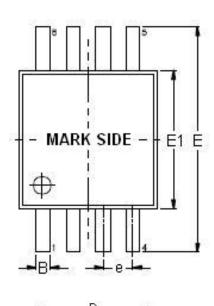


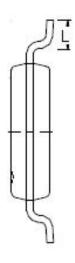
Tape Size	Pocket Pitch	Reel Size (A)		Reel Width	Empty Cavity	Units per Reel
(W1) mm	(P) mm	in	mm	(W2) mm	Length mm	
8	4	7	180	8.4	300~1000	3,000



Outline Information (Continued)

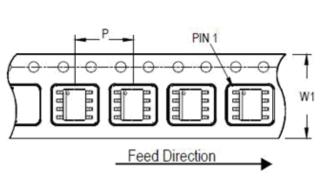
MSOP-8 Package (Unit: mm)

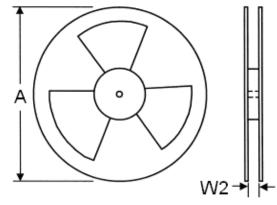




SYMBOLS	DIMENSION IN MILLIMETER			
UNIT	MIN	MAX		
Α	0.75	1.10		
A1	0.00	0.15		
A2	A2 0.75 0.95			
В	0.25	0.35		
D	2.90	3.10		
E	4.80	5.00		
E1	2.90	3.10		
е	0.60	0.70		
L	0.40	0.80		

Carrier Dimensions





Tape Size	Pocket Pitch	Reel Size (A)		Reel Width	Empty Cavity	Units per Reel
(W1) mm	(P) mm	in	mm	(W2) mm	Length mm	
12	8	13	330	12.4	400~1000	3,000

Life Support Policy
Fitipower's products are not authorized for use as critical components in life support devices or other medical systems.